## VS-E5TX3012-M3

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Vishay Semiconductors

# Hyperfast Rectifier, 30 A FRED Pt<sup>®</sup> G5



### LINKS TO ADDITIONAL RESOURCES



PRIMARY CHARACTERISTICS							
I <sub>F(AV)</sub> 30 A							
V <sub>R</sub>	1200 V						
V <sub>F</sub> at I <sub>F</sub> at 125 °C	2.1 V						
t <sub>rr</sub>	26 ns						
T <sub>J</sub> max.	175 °C						
Package TO-220AC 2L							
Circuit configuration	Single						

### **FEATURES**

- Hyperfast and optimized Q<sub>rr</sub>



FREE

- Best in class forward voltage drop and switching RoHS losses trade off COMPLIANT HALOGEN
- · Optimized for high speed operation
- 175 °C maximum operating junction temperature
- Polyimide passivation
- Material categorization: for definitions of compliance please see www.vishay.com/doc?99912

#### **DESCRIPTION / APPLICATIONS**

Featuring a unique combination of low conduction and switching losses, this rectifier is the right choice for high frequency converters, both soft switched / resonant.

Specifically designed to improve efficiency of PFC and output rectification stages of EV / HEV battery charging stations, booster stage of solar inverters and UPS applications, these devices are perfectly matched to operate with MOSFETs or high speed IGBTs.

#### **MECHANICAL DATA**

#### Case: TO-220AC 2L

Molding compound meets UL 94 V-0 flammability rating

Terminals: matte tin plated leads, solderable per J-STD-002 and JESD 22-B102

Polarity: as per marking device details

ABSOLUTE MAXIMUM RATINGS								
PARAMETER	SYMBOL	TEST CONDITIONS	VALUES	UNITS				
Repetitive peak reverse voltage	V <sub>RRM</sub>		1200	V				
Average rectified forward current	I <sub>F(AV)</sub>	T <sub>C</sub> = 83 °C, D = 0.50	30					
Non-repetitive peak surge current	I <sub>FSM</sub>	$T_{C}$ = 83 °C, $t_{p}$ = 10 ms, sine wave	190	А				
Repetitive peak forward current	I <sub>FRM</sub>	T <sub>C</sub> = 45 °C, D = 0.50, f = 20 kHz	60					
Operating junction and storage temperature	T <sub>J</sub> , T <sub>Stg</sub>		-55 to +175	°C				

<b>ELECTRICAL SPECIFICATIONS</b> (T <sub>J</sub> = 25 $^{\circ}$ C unless otherwise specified)								
PARAMETER	SYMBOL	TEST CONDITIONS MIN. TYP. M				UNITS		
Breakdown voltage, blocking voltage	V <sub>BR</sub> , V <sub>R</sub>	I <sub>R</sub> = 100 μA	1200	-	-			
E	V <sub>F</sub>	I <sub>F</sub> = 30 A	-	2.6	3.3	V		
Forward voltage		I <sub>F</sub> = 30 A, T <sub>J</sub> = 125 °C	-	2.1	-			
Deverage lookage everyont	I <sub>R</sub>	$V_{R} = V_{R}$ rated	-	-	50			
Reverse leakage current		$T_J = 125 \text{ °C}, V_R = V_R \text{ rated}$	-	-	500	μA		
Junction capacitance	CT	V <sub>R</sub> = 200 V	-	17	-	pF		
Series inductance	L <sub>S</sub>	Measured to lead 5 mm from package body	-	8	-	nH		

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DYNAMIC RECOVERY	CHARACTERI	<b>STICS</b> $(T_J = 25)$	°C unless otherwi	se speci	fied)		
PARAMETER	SYMBOL	TEST CONDITIONS		MIN.	TYP.	MAX.	UNITS
		$I_F = 1.0 \text{ A}, \text{ d}I_F/\text{d}t$	= 100 A/µs, V <sub>R</sub> = 30 V	-	26	47	
Reverse recovery time	t <sub>rr</sub>	T <sub>J</sub> = 25 °C		-	100	-	ns
		T <sub>J</sub> = 125 °C		-	150	-	1
Peak recovery current	1	T <sub>J</sub> = 25 °C	I <sub>F</sub> = 20 A dI <sub>F</sub> /dt = 600 A/μs	-	12	-	A
	I <sub>RRM</sub>	T <sub>J</sub> = 125 °C	$V_{\rm R} = 400 \text{ V}$	-	22	-	
<b>_</b>	0	T <sub>J</sub> = 25 °C		-	530	-	nC
Reverse recovery charge	Q <sub>rr</sub>	T <sub>J</sub> = 125 °C		-	1650	-	
Povereo recovery time	+	T <sub>J</sub> = 25 °C		-	80	-	
Reverse recovery time	t <sub>rr</sub>	T <sub>J</sub> = 125 °C		-	120	-	ns
Deals receivers everyont	1	T <sub>J</sub> = 25 °C	$I_{\rm F} = 30  {\rm A}$	-	22	-	A
Peak recovery current	IRRM	T <sub>J</sub> = 125 °C	<ul> <li>dI<sub>F</sub>/dt = 1000 A/μs</li> <li>V<sub>B</sub> = 800 V</li> </ul>	-	37	-	
	0	T <sub>J</sub> = 25 °C		-	900	-	nC
Reverse recovery charge	Q <sub>rr</sub>	T <sub>J</sub> = 125 °C	1	-	2400	-	

THERMAL - MECHANICAL SPECIFICATIONS									
PARAMETER	SYMBOL	TEST CONDITIONS	MIN.	TYP.	MAX.	UNITS			
Thermal resistance, junction-to-case	R <sub>thJC</sub>		-	-	1.1	°C/W			
Weight			-	2.0	-	g			
Weight			-	0.07	-	oz.			
Mounting torque			6.0 (5.0)	-	12 (10)	kgf · cm (lbf · in)			
Maximum junction and storage temperature range	T <sub>J</sub> , T <sub>Stg</sub>		-55	-	175	°C			
Marking device		Case style: TO-220AC 2L	E5TX3012						

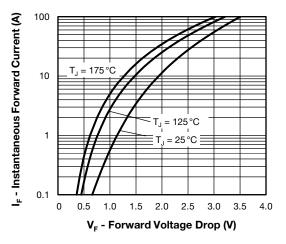


Fig. 1 - Typical Forward Voltage Drop Characteristics

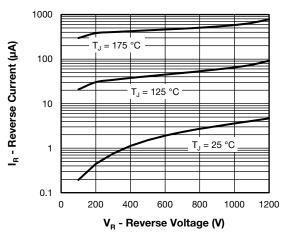
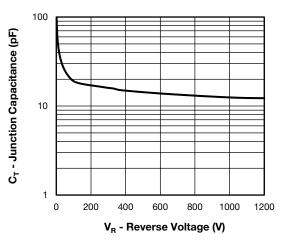


Fig. 2 - Typical Values of Reverse Current vs. Reverse Voltage

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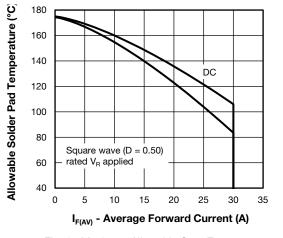
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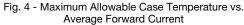


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Fig. 3 - Typical Junction Capacitance vs. Reverse Voltage





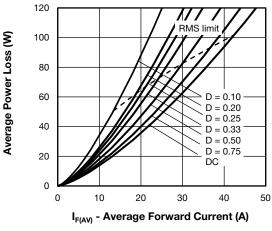


Fig. 5 - Typical Recovery Current vs. dl<sub>F</sub>/dt

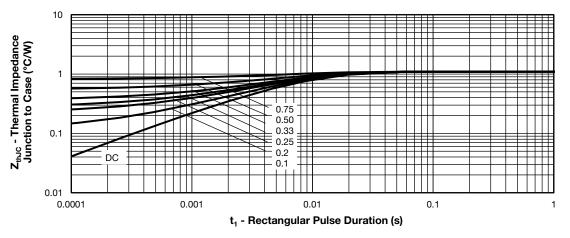


Fig. 6 - Thermal Impedance ZthJC Characteristics

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20 A, 400 V

 $T_J = 125 \,^{\circ}C$ 

1000

1200

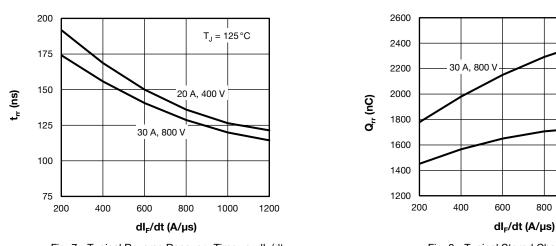


Fig. 7 - Typical Reverse Recovery Time vs. dl<sub>F</sub>/dt

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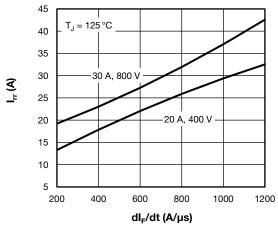


Fig. 9 - Typical Recovery Current vs. dl<sub>F</sub>/dt

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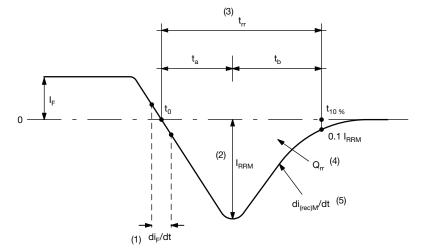


Fig. 10 - Reverse Recovery Waveform and Definitions

Notes

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 $^{(1)}~di_{F}/dt$  - rate of change of current through zero crossing

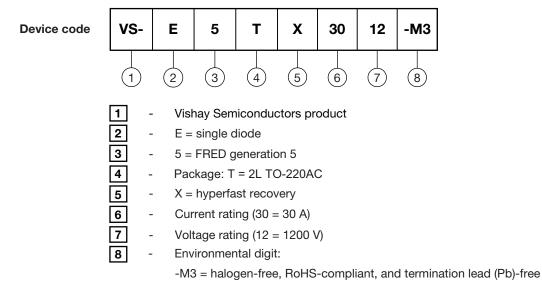
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- <sup>(2)</sup> I<sub>RRM</sub> peak reverse recovery current
- (3)  $t_{rr}$  reverse recovery time measured from  $t_0$ , crossing point of negative going I<sub>F</sub>, to point  $t_{10\%}$ , 0.1 I<sub>RRM</sub>
- $^{(4)}~~Q_{rr}$  area under curve defined by  $t_0$  and  $t_{10}~\%$

$$Q_{rr} = \int_{t_{r}}^{t_{10\%}} I(t) dt$$

 $^{(5)}$  di<sub>(rec)</sub>M/dt - peak rate of change of current during t<sub>b</sub> portion of t<sub>rr</sub>

#### **ORDERING INFORMATION TABLE**



ORDERING INFORMATION (Example)							
PREFERRED P/N BASE QUANTITY PACKAGING DESCRIPTION							
VS-E5TX3012-M3	50	Antistatic plastic tubes					

LINKS TO RELATED DOCUMENTS					
Dimensions	www.vishay.com/doc?96154				
Part marking information	www.vishay.com/doc?95391				

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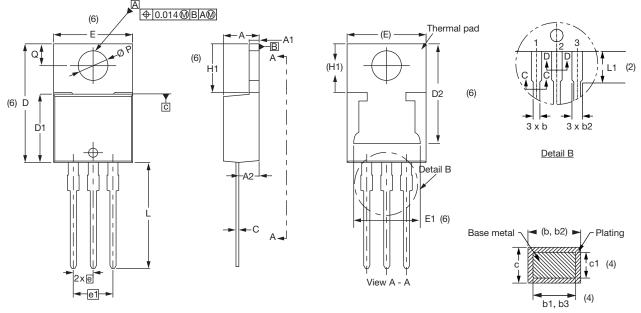


## **Outline Dimensions**

**Vishay Semiconductors** 

# 3L TO-220AB

### **DIMENSIONS** in millimeters and inches



Section C - C and D - D



Conforms	to	<b>JEDEC</b> <sup>®</sup>	outline	<b>TO-220AB</b>
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SYMBOL	MILLIN	IETERS	INCHES		NOTES
STMBOL	MIN.	MAX.	MIN.	MAX.	NOTES
A	4.25	4.65	0.167	0.183	
A1	1.14	1.40	0.045	0.055	
A2	2.50	2.92	0.098	0.115	
b	0.69	1.01	0.027	0.040	
b1	0.38	0.97	0.015	0.038	4
b2	1.20	1.73	0.047	0.068	
b3	1.14	1.73	0.045	0.068	4
с	0.36	0.61	0.014	0.024	
c1	0.36	0.56	0.014	0.022	4
D	14.85	15.35	0.585	0.604	3
D1	8.38	9.02	0.330	0.355	

SYMBOL	MILLIN	IETERS	INC	HES	NOTES
STIVIDOL	MIN.	MAX.	MIN.	MAX.	NOTES
D2	11.68	13.30	0.460	0.524	6, 7
E	10.11	10.51	0.398	0.414	3, 6
E1	6.86	8.89	0.270	0.350	6
е	2.41	2.67	0.095	0.105	
e1	4.88	5.28	0.192	0.208	
H1	6.09	6.48	0.240	0.255	6
L	13.52	14.02	0.532	0.552	
L1	3.32	3.82	0.131	0.150	2
ØР	3.54	3.91	0.139	0.154	
Q	2.60	3.00	0.102	0.118	

#### Notes

- <sup>(1)</sup> Dimensioning and tolerancing as per ASME Y14.5M-1994
- <sup>(2)</sup> Lead dimension and finish uncontrolled in L1
- <sup>(3)</sup> Dimension D, D1, and E do not include mold flash. Mold flash shall not exceed 0.127 mm (0.005") per side. These dimensions are measured at the outermost extremes of the plastic body
- <sup>(4)</sup> Dimension b1, b3, and c1 apply to base metal only
- <sup>(5)</sup> Controlling dimensions: inches
- <sup>(6)</sup> Thermal pad contour optional within dimensions E, H1, D2, and E1
- <sup>(7)</sup> Outline conforms to JEDEC<sup>®</sup> TO-220, except D2





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